

Abderraouf Boucherif

List of Publications by Year in descending order

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32
papers

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1040056

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h-index

888059

17
g-index

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docs citations

33
times ranked

345
citing authors

| # | ARTICLE | IF | CITATIONS |
|----|---|------|-----------|
| 1 | Uprooting defects to enable high-performance III-V optoelectronic devices on silicon. <i>Nature Communications</i> , 2019, 10, 4322. | 12.8 | 44 |
| 2 | Chemical Composition of Nanoporous Layer Formed by Electrochemical Etching of p-Type GaAs. <i>Nanoscale Research Letters</i> , 2016, 11, 446. | 5.7 | 39 |
| 3 | Fast growth synthesis of mesoporous germanium films by high frequency bipolar electrochemical etching. <i>Electrochimica Acta</i> , 2017, 232, 422-430. | 5.2 | 33 |
| 4 | Multijunction Solar Cell Designs Using Silicon Bottom Subcell and Porous Silicon Compliant Membrane. <i>IEEE Journal of Photovoltaics</i> , 2013, 3, 1125-1131. | 2.5 | 25 |
| 5 | Tunable conductivity in mesoporous germanium. <i>Nanotechnology</i> , 2018, 29, 215701. | 2.6 | 17 |
| 6 | Novel multijunction solar cell design for low cost, high concentration systems. <i>Progress in Photovoltaics: Research and Applications</i> , 2016, 24, 150-158. | 8.1 | 16 |
| 7 | Anisotropic mesoporous germanium nanostructures by fast bipolar electrochemical etching. <i>Electrochimica Acta</i> , 2021, 378, 137935. | 5.2 | 15 |
| 8 | Tamm phonon-polaritons: Localized states from phonon-light interactions. <i>Applied Physics Letters</i> , 2019, 114, . | 3.3 | 14 |
| 9 | Graphene-Mesoporous Si Nanocomposite as a Compliant Substrate for Heteroepitaxy. <i>Small</i> , 2017, 13, 1603269. | 10.0 | 11 |
| 10 | Extreme temperature stability of thermally insulating graphene-mesoporous-silicon nanocomposite. <i>Nanotechnology</i> , 2018, 29, 145701. | 2.6 | 9 |
| 11 | Al-enhanced N incorporation in GaNAs alloys grown by chemical beam epitaxy. <i>Journal of Crystal Growth</i> , 2013, 380, 256-260. | 1.5 | 8 |
| 12 | Structural, optical and terahertz properties of graphene-mesoporous silicon nanocomposites. <i>Nanoscale Advances</i> , 2020, 2, 340-346. | 4.6 | 8 |
| 13 | Cost-effective energy harvesting at ultra-high concentration with duplicated concentrated photovoltaic solar cells. <i>Energy Science and Engineering</i> , 2020, 8, 2760-2770. | 4.0 | 8 |
| 14 | Control of mesoporous silicon initiation by cathodic passivation. <i>Electrochemistry Communications</i> , 2013, 36, 84-87. | 4.7 | 7 |
| 15 | Growth optimization and optical properties of AlGaAs alloys. <i>Journal of Applied Physics</i> , 2014, 115, . | 2.5 | 7 |
| 16 | CVD growth of high-quality graphene over Ge (100) by annihilation of thermal pits. <i>Carbon</i> , 2021, 174, 214-226. | 10.3 | 7 |
| 17 | Near-infrared emission from mesoporous crystalline germanium. <i>AIP Advances</i> , 2014, 4, 107128. | 1.3 | 6 |
| 18 | Metastable States in Pressurized Bulk and Mesoporous Germanium. <i>Journal of Physical Chemistry C</i> , 2018, 122, 10929-10938. | 3.1 | 6 |

| # | ARTICLE | IF | CITATIONS |
|----|--|------|-----------|
| 19 | Integration of 3D nanographene into mesoporous germanium. <i>Nanoscale</i> , 2020, 12, 23984-23994. | 5.6 | 6 |
| 20 | Shape control of cathodized germanium oxide nanoparticles. <i>Electrochemistry Communications</i> , 2021, 122, 106906. | 4.7 | 6 |
| 21 | A porous Ge/Si interface layer for defect-free III-V multi-junction solar cells on silicon. , 2019, , . | | 5 |
| 22 | In-situ Transmission Electron Microscopy Observation of Germanium Growth on Freestanding Graphene: Unfolding Mechanism of 3D Crystal Growth During Van der Waals Epitaxy. <i>Small</i> , 2022, 18, e2101890. | 10.0 | 5 |
| 23 | Growth of Ge epilayers using iso-butylgermane (IBGe) and its memory effect in an III-V chemical beam epitaxy reactor. <i>Journal of Crystal Growth</i> , 2020, 547, 125807. | 1.5 | 4 |
| 24 | Monolithic integration of mesoporous germanium: A step toward high-performance on-chip anode. <i>Materials Today Communications</i> , 2021, 26, 101820. | 1.9 | 4 |
| 25 | Electrical and structural properties of AlGaAs alloys grown by chemical beam epitaxy. <i>Physica Status Solidi (B): Basic Research</i> , 2016, 253, 918-922. | 1.5 | 3 |
| 26 | Optimization of p-doping in AlGaAs grown by CBE using TMA for AlGaAs/GaAs tunnel junctions. <i>Journal of Crystal Growth</i> , 2013, 374, 1-4. | 1.5 | 2 |
| 27 | III-V Multi-Junction Solar Cells on Si Substrates with a Voided Ge Interface Layer: A Modeling Study. , 2018, , . | | 2 |
| 28 | Effect of sintering germanium epilayers on dislocation dynamics: From theory to experimental observation. <i>Acta Materialia</i> , 2020, 200, 608-618. | 7.9 | 2 |
| 29 | Probing the coupling between the components in a graphene-mesoporous germanium nanocomposite using high-pressure Raman spectroscopy. <i>Nanoscale Advances</i> , 2021, 3, 2577-2584. | 4.6 | 2 |
| 30 | Engineering dislocations and nanovoids for high-efficiency III-V photovoltaic cells on silicon. <i>AIP Conference Proceedings</i> , 2020, , . | 0.4 | 2 |
| 31 | Capturing the Effects of Free Surfaces on Threading Dislocation Density Reduction. <i>ECS Transactions</i> , 2020, 98, 527-532. | 0.5 | 1 |
| 32 | Effect of voided germanium thin-films grown onto silicon substrate on dislocations evolution. , 2021, , . | | 0 |